Second Order Optical Nonlinearity in Glassy Material and Some Applications

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- Basic Concept of Nonlinear Optics
- Phase-Matching
- Quasi-Phase-Matching (QPM)
- QPM-SHG of Blue Light in Nonlinear Crystal
- Creating Second Order Nonlinearity in Glass
- How to Implement QPM in Glass
- QPM-SHG in Glass

Some Basics of Nonlinear Optics

Hook's Law F=Ky

x= + F



In case of monlinearity : K(F)

Dielectric response : $\vec{p} = \chi(\vec{e}) \vec{E}$

 $\vec{P} = \chi^{(0)} \vec{e} + \chi^{(2)} \vec{e} \vec{e} + \chi^{(2)} \vec{e} \vec{e} \vec{e} \vec{e} + \dots$

 $P_{i} = \sum_{j} \chi_{ij}^{(i)} E_{j} + \sum_{j} \sum_{k} \chi_{ijk}^{(i)} E_{j} E_{k}$

+ ZZX Xijke Ej Ek Er +

i.j.k.l=1.2.3. or x.J.Z.

Linear Case: $\vec{P} = \vec{X}\vec{E}$ $\vec{P}_{i} = \vec{\Sigma}\vec{X}_{ij}^{(o)}\vec{E}_{j}$

$$\overline{P}(\overline{r}, t) = \chi(\overline{r}, t) \overline{E}(\overline{r}, t) ???$$

$$P_{i}(\overline{r}, t) = \sum_{i} \chi_{ij}^{(0)}(\overline{r}, t) \overline{E}_{i}(\overline{r}, t) ??$$

For lossy material and non-local interaction: $P_i(\vec{r}, t) = \sum_{j} \int \chi^{(0)}(\vec{r} - \vec{r}', t - t') E_j(\vec{r}', t') d\vec{r}' dt', \quad t' > t$ For lossy material and non-local interaction: $P_{i}(\vec{r},t) = \sum_{d} \int \int \mathcal{A}_{ij}^{(0)}(\vec{r}-\vec{r}',t-t') E_{j}(\vec{r}',t') d\vec{r}' dt', \quad \mathcal{X}=0$ when t'>t

From convolution theorem : (f(t)=Sh(t-t')g(t)dt'=>F(w)=H(w)G(w))

$$P_{i}(\bar{k}, \omega) = \sum_{j} \chi_{ij}^{(0)}(\bar{k}, \omega) E_{j}(\bar{k}, \omega) \left(\bar{P}_{i}(\bar{k}, \omega) = \chi^{(0)}(\bar{k}, \omega) \bar{E}(\bar{k}, \omega) \right)$$

Same for nonlinear case :

$$P_{i}(\tau,t) = \sum_{j} \gamma_{j}^{(e)}(\tau-\tau',t-t') = \sum_{j} (\tau',t') + \sum_{j} \sum_{k} \gamma_{jk}^{(e)}(\tau-\tau',\tau-\tau'',t-t',t-t'') = (\tau',t') = (\tau',$$

S.

$$P_{i}(\bar{\mathbf{r}},\omega) = \sum_{j} \chi_{ij}^{(o)}(\bar{\mathbf{r}},\omega) E_{j}(\bar{\mathbf{r}},\omega) + \sum_{j} \sum_{k} \chi_{ijk}^{(2)}(\bar{\mathbf{r}} = \bar{\mathbf{r}},t\bar{\mathbf{r}}_{2},\omega=\omega,t\omega_{2}) E_{j}(\bar{\mathbf{r}}_{1},\omega_{1}) E_{k}(\bar{\mathbf{r}}_{2},\omega_{2}) + \sum_{j} \sum_{k} \chi_{ijk}^{(3)}(\bar{\mathbf{r}} = \bar{\mathbf{r}},t\bar{\mathbf{r}}_{2},t\bar{\mathbf{r}}_{2},\omega_{2}) E_{k}(\bar{\mathbf{r}}_{2},\omega_{2}) E_{$$



There is no second order nonlinear effect for material with central symmetry.



phase Matching

Example : second harmonic generation (SHG)

 $\overrightarrow{P}^{(2)}(\overrightarrow{k}=\overrightarrow{F},\overrightarrow{F},\overrightarrow{F},\psi=\omega,\pm\omega)=\overrightarrow{T}^{(2)}(\overrightarrow{F},\omega)\overrightarrow{E}(\overrightarrow{F},\omega,\overrightarrow{F},\overline{E},\overline{E},\omega)$

For SHG $W_1 = W_2$ $W = 2W_1$ $\overline{k}_1 = \overline{k}_2$ $\overline{k} = 2\overline{k}_1$



SHG Power Conversion

$$\eta = \frac{P_{2\omega}}{P_{\omega}} = 2 \left(\frac{\mu}{\varepsilon_0}\right)^{\frac{3}{2}} \cdot \frac{\omega^2 d_{eff}^2}{n_{\omega}^2 n_{2\omega}} \cdot \sin c^2 \left(\frac{\Delta kL}{2}\right) \cdot \frac{L^2 P_{\omega}}{A}$$

$$\Delta k = k_{2\omega} - 2k_{\omega}$$

$$l_{c} = \frac{2\pi}{\Delta k} = \frac{\lambda}{4(n_{2\omega} - n_{\omega})}$$
coherence length

SHG in Waveguide $k_{\omega} \rightarrow \beta_{\omega}^{p}$ $\frac{1}{A} \rightarrow (overlap integral)^{2}$ $k_{2\omega} \rightarrow \beta_{2\omega}^{q}$ $= \left[\iint E_{2\omega}^{q} \cdot E_{\omega}^{p} E_{\omega}^{p*} dx dy\right]^{2}$



Quasi-Phase-Matching

Historical

 1962 Armstrong, Bloembergen, Ducning, Pershan Phys. Rev. 127, 1918

$$\vec{P}(\omega_3) = \varepsilon_0 \quad \vec{\chi}^{(2)}: \vec{E}(\omega_1)\vec{E}(\omega_2)$$

$$\Delta \vec{K} = \vec{K}_3 - \vec{K}_2 - \vec{K}_1 + \frac{2\pi}{\Lambda}\hat{k} = 0$$

$$\Lambda: \text{ periode of periodical reversal of } \chi^{(2)}$$

Quasi-Phase-Matching (Periodic reversal of $\chi^{(2)}$)

Periodic insertion of crystal with an inverted crystal orientation
 Periodic reversal of ferroelectric domain of nonlinear crystal
 (periodic poling)

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Bulk coupling



End-fire coupling to waveguide





Second Harmonic Generation



光資訊儲存實驗室

Periodic Poling





Poling apparatus







Results

PPLT

Uniform, straight and precise duty structure achieved for 3rd QPM-SHG

Different period structure viewed from samples' edge 100 um 30 u







Bulk coupling





Opt. Info. Lab.

QPM-SHG of blue light in PPLT

- Fabrication of PPLT realized
- Poling mechanism understood and QPM-SHG quality improved
- Generation of 1st (3.8um), 3rd (11.4um) order QPM-SHG blue light in bulk and in proton exchanged waveguide were achieved



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Fundamental wavelength scan



PPLT

Opt. Info. Lab.

Fundamental wavelength scan



Opt. Info. Lab.



Second Order Nonlinearity in Glass Material

• $P = \chi^{(0)} E + \chi^{(2)} E E + \chi^{(3)} E E E + \dots$

• $\chi^{(2)} = 0$ for glass (centro-symmetric) but if $\chi^{(3)} EEE = \chi^{(3)} E_{dc} EE = \chi^{(2)} EE$ with $\chi^{(3)} E_{dc} = \chi^{(2)}$

 E_{dc} : built-in dc field

E-field induced Mechanisms (I)

Selectric-field-induced second-harmonic generation (EFISHG)

where

for centro-symmetric medium



Creation of Built-in Field in Silica Glass : Thermal Poling

Under high Temperature and high dc voltage ,a intense electric field (E_{dc}) is established for orientation of bonds near the anode surface the. =>depletion region of E_{dc} break centosymmetric => $\chi^{(2)} = 3 \chi^{(3)}E_{dc}$



Fig. 3. Planar schematic diagram of silica network before poling.



Fig. 7. Planar schematic diagram of silica network after poling.

(D)Depletion region generation process:



Fig. 5. Formation process of the depletion region near the anode surface in the multiple-carrier model. (a) The primary process from scores of milliseconds to several seconds in the TEFP; (b) from several seconds to scores of seconds in the TEFP; (c) after several seconds in the TEFP; (d) the state after scores of milliseconds reach the quasi-steady state.

$$\equiv Si - O - \equiv Si + H_2O \implies 2 \equiv Si - OH$$
$$\equiv Si - OH + H_2O \implies \equiv Si - O^- + H_3O^+$$
$$\equiv Si - O^- \implies \equiv Si - O + e^-$$

Maker fringe setup



Maker fringe measurement



How to implement QPM in glass?

UV erasure of second-order nonlinearity





Periodic poling & etched profile





Device fabrication













QPM-SHG in Ge ion-implanted nonlinear optical channel waveguides

Fabrication flow chart



Periodical UV-erasure of second order nonlinearity



8 difference period

Poling & UV-erasure characteristic



Future applications Silica-based active device on Si wafer



Silica-based EO device [8]





Silica-based MZ interferometer [9]

Frequency conversion device EO modulator switch

